8-Bit Serial-Input/Parallel-Output Shift Register

High-Performance Silicon-Gate CMOS

The MC74HC164A is identical in pinout to the LS164. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The MC74HC164A is an 8-bit, serial-input to parallel-output shift register. Two serial data inputs, A1 and A2, are provided so that one input may be used as a data enable. Data is entered on each rising edge of the clock. The active-low asynchronous Reset overrides the Clock and Serial Data inputs.

Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 V to 6.0 V
- Low Input Current: 1 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the JEDEC Standard No. 7 A Requirements
- Chip Complexity: 244 FETs or 61 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



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MARKING DIAGRAMS

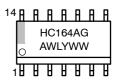


PDIP-14 N SUFFIX CASE 646





SOIC-14 D SUFFIX CASE 751A





1

TSSOP-14 DT SUFFIX CASE 948G



A = Assembly Location

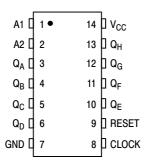
L, WL = Wafer Lot Y, YY = Year W, WW = Work Week G or ■ = Pb-Free Package

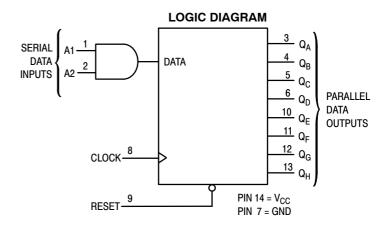
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

PIN ASSIGNMENT





FUNCTION TABLE

| | Inpu | ts | | | Outp | uts | |
|-------|-------|------------|----|-------|----------|------|----------|
| Reset | Clock | A 1 | A2 | Q_A | Q_B | | Q_{H} |
| L | Х | Х | Х | L | L | | L |
| Н | ~ | Х | Χ | | No Ch | ange | Э |
| Н | | Н | D | D | Q_{An} | | Q_{Gn} |
| Н | | D | Н | D | Q_{An} | | Q_{Gn} |

D = data input

 $Q_{An}-Q_{Gn}=$ data shifted from the preceding stage on a rising edge at the clock input.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------------|-----------------------|-----------------------|
| MC74HC164ANG | PDIP-14 (Pb-Free) | 25 Units / Rail |
| MC74HC164ADG | SOIC-14 (Pb-Free) | 55 Units / Rail |
| MC74HC164ADR2G | SOIC-14 (Pb-Free) | 2500 / Tape & Reel |
| MC74HC164ADTR2G | TSSOP-14 (Pb-Free) | 2500 / Tape & Reel |
| NLV74HC164ADR2G* | SOIC-14 (Pb-Free) | 2500 / Tape & Reel |
| NLV74HC164ADTR2G* | TSSOP-14 (Pb-Free) | 2500 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------------|---|--------------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | - 0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage (Referenced to GND) | -0.5 to V_{CC} + 0.5 | V |
| V _{out} | DC Output Voltage (Referenced to GND) | -0.5 to V_{CC} + 0.5 | V |
| I _{in} | DC Input Current, per Pin | ± 20 | mA |
| l _{out} | DC Output Current, per Pin | ± 25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ± 50 | mA |
| P _D | Power Dissipation in Still Air, Plastic DIP† SOIC Package† TSSOP Package† | 750 500 450 | mW |
| T _{stg} | Storage Temperature | - 65 to + 150 | °C |
| TL | Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP, SOIC or TSSOP Package) | 260 | °C |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC} .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

†Derating — Plastic DIP: – 10 mW/°C from 65° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

TSSOP Package: - 6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|------------------------------------|--|------|--------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | 2.0 | 6.0 | V |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage (Referenced to GND) | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | - 55 | + 125 | °C |
| t _r , t _f | Input Rise and Fall Time $V_{CC} = 2.0^{\circ}$ (Figure 1) $V_{CC} = 4.5^{\circ}$ $V_{CC} = 6.0^{\circ}$ | / 0 | 1000 500 400 | ns |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| | | | | Guaranteed Limit | | | |
|-----------------|--------------------------------------|---|--------------------------|---------------------------|---------------------------|---------------------------|------|
| Symbol | Parameter | Test Conditions | V _{CC} V | -55°C to 25°C | ≤ 85 °C | ≤ 125°C | Unit |
| V _{IH} | Minimum High-Level Input Voltage | V_{out} = 0.1 V or V_{CC} – 0.1 V $ I_{out} \le 20 \mu A$ | 2.0 3.0 4.5 6.0 | 1.5 2.1 3.15 4.2 | 1.5 2.1 3.15 4.2 | 1.5 2.1 3.15 4.2 | V |
| V _{IL} | Maximum Low-Level Input Voltage | $V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \mu\text{A}$ | 2.0 3.0 4.5 6.0 | 0.5 0.9 1.35 1.8 | 0.5 0.9 1.35 1.8 | 0.5 0.9 1.35 1.8 | V |
| V _{OH} | Minimum High-Level Output Voltage | $V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \mu\text{A}$ | 2.0 4.5 6.0 | 1.9 4.4 5.9 | 1.9 4.4 5.9 | 1.9 4.4 5.9 | V |
| | | $\label{eq:Vin} \begin{aligned} V_{in} = V_{IH} \text{ or } V_{IL} & & I_{out} \leq 2.4 \text{ mA} \\ & & I_{out} \leq 4.0 \text{ mA} \\ & & I_{out} \leq 5.2 \text{ mA} \end{aligned}$ | | 2.48 3.98 5.48 | 2.34 3.84 5.34 | 2.20 3.70 5.20 | |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| | | | | Guaranteed Limit | | | |
|-----------------|---|---|-----------------|------------------|--------|---------|------|
| Symbol | Parameter | Test Conditions | v _{cc} | –55°C to 25°C | ≤ 85°C | ≤ 125°C | Unit |
| V _{OL} | Maximum Low-Level Output | V _{in} = V _{IH} or V _{IL} | 2.0 | 0.1 | 0.1 | 0.1 | V |
| | Voltage | $ I_{out} \leq 20 \mu A$ | 4.5 | 0.1 | 0.1 | 0.1 | |
| | | | 6.0 | 0.1 | 0.1 | 0.1 | |
| | | $V_{in} = V_{IH} \text{ or } V_{IL} I_{out} \leq 2.4 \text{ mA}$ | 3.0 | 0.26 | 0.33 | 0.40 | |
| | | $ I_{\text{out}} \leq 4.0 \text{ mA}$ | 4.5 | 0.26 | 0.33 | 0.40 | |
| | | $ I_{out} \le 5.2 \text{ mA}$ | 6.0 | 0.26 | 0.33 | 0.40 | |
| l _{in} | Maximum Input Leakage Current | V _{in} = V _{CC} or GND | 6.0 | ± 0.1 | ± 1.0 | ± 1.0 | μΑ |
| I _{CC} | Maximum Quiescent Supply Current (per Package) | $V_{in} = V_{CC}$ or GND $I_{out} = 0 \mu A$ | 6.0 | 4 | 40 | 160 | μΑ |

AC ELECTRICAL CHARACTERISTICS (C $_L$ = 50 pF, Input $t_{\rm f}$ = $t_{\rm f}$ = 6 ns)

| | | | Guaranteed Limit | | | |
|--|---|--------------------------|------------------------|------------------------|------------------------|------|
| Symbol | Parameter | V _{CC} | –55°C to 25°C | ≤ 85 °C | ≤ 125°C | Unit |
| f _{max} | Maximum Clock Frequency (50% Duty Cycle) (Figures 1 and 4) | 2.0 3.0 4.5 6.0 | 10 20 40 50 | 10 20 35 45 | 10 20 30 40 | MHz |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Clock to Q (Figures 1 and 4) | 2.0 3.0 4.5 6.0 | 160 100 32 27 | 200 150 40 34 | 250 200 48 42 | ns |
| t _{PHL} | Maximum Propagation Delay, Reset to Q (Figures 2 and 4) | 2.0 3.0 4.5 6.0 | 175 100 35 30 | 220 150 44 37 | 260 200 53 45 | ns |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, Any Output (Figures 1 and 4) | 2.0 3.0 4.5 6.0 | 75 27 15 13 | 95 32 19 16 | 110 36 22 19 | ns |
| C _{in} | Maximum Input Capacitance | _ | 10 | 10 | 10 | pF |
| | | | Typical | @ 25°C, V _C | _C = 5.0 V | |

| | | Typical @ 25°C, V _{CC} = 5.0 V | |
|----------|--|---|----|
| C_{PD} | Power Dissipation Capacitance (Per Package)* | 180 | pF |

TIMING REQUIREMENTS (Input $t_r = t_f = 6 \text{ ns}$)

| | | | | Guaranteed Limit | | | |
|---------------------------------|---|--------------------------|---------------------------|---------------------------|---------------------------|------|--|
| Symbol | Parameter | V _{CC} | –55°C to 25°C | ≤ 85 °C | ≤ 125°C | Unit | |
| t _{su} | Minimum Setup Time, A1 or A2 to Clock (Figure 3) | 2.0 3.0 4.5 6.0 | 25 15 7 5 | 35 20 8 6 | 40 25 9 6 | ns | |
| t _h | Minimum Hold Time, Clock to A1 or A2 (Figure 3) | 2.0 3.0 4.5 6.0 | 3 3 3 3 | 3 3 3 3 | 3 3 3 3 | ns | |
| t _{rec} | Minimum Recovery Time, Reset Inactive to Clock (Figure 2) | 2.0 3.0 4.5 6.0 | 3 3 3 3 | 3 3 3 3 | 3 3 3 3 | ns | |
| t _w | Minimum Pulse Width, Clock (Figure 1) | 2.0 3.0 4.5 6.0 | 50 26 12 10 | 60 35 15 12 | 75 45 20 15 | ns | |
| t _w | Minimum Pulse Width, Reset (Figure 2) | 2.0 3.0 4.5 6.0 | 50 26 12 10 | 60 35 15 12 | 75 45 20 15 | ns | |
| t _r , t _f | Maximum Input Rise and Fall Times (Figure 1) | 2.0 3.0 4.5 6.0 | 1000 800 500 400 | 1000 800 500 400 | 1000 800 500 400 | ns | |

PIN DESCRIPTIONS

INPUTS

A1, A2 (Pins 1, 2)

Serial Data Inputs. Data at these inputs determine the data to be entered into the first stage of the shift register. For a high level to be entered into the shift register, both A1 and A2 inputs must be high, thereby allowing one input to be used as a data–enable input. When only one serial input is used, the other must be connected to $V_{\rm CC}$.

Clock (Pin 8)

Shift Register Clock. A positive-going transition on this pin shifts the data at each stage to the next stage. The shift

register is completely static, allowing clock rates down to DC in a continuous or intermittent mode.

OUTPUTS

Q_A - Q_H (Pins 3, 4, 5, 6, 10, 11, 12, 13)

Parallel Shift Register Outputs. The shifted data is presented at these outputs in true, or noninverted, form.

CONTROL INPUT

Reset (Pin 9)

Active–Low, Asynchronous Reset Input. A low voltage applied to this input resets all internal flip–flops and sets Outputs Q_A – Q_H to the low level state.

SWITCHING WAVEFORMS

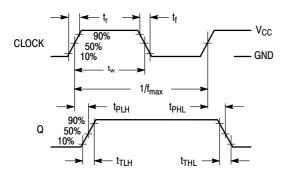


Figure 1.

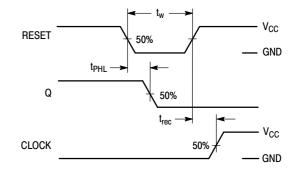


Figure 2.

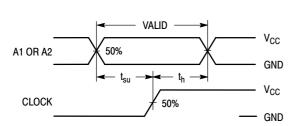
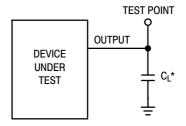


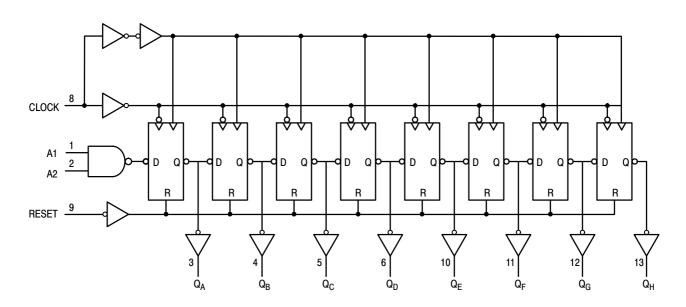
Figure 3.



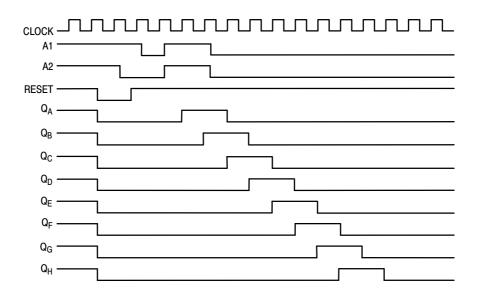
*Includes all probe and jig capacitance

Figure 4. Test Circuit

EXPANDED LOGIC DIAGRAM

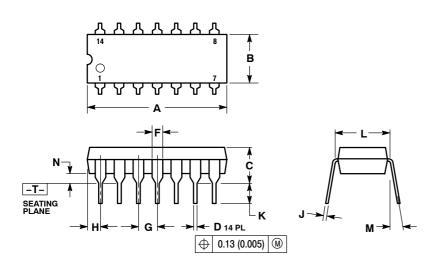


TIMING DIAGRAM



PACKAGE DIMENSIONS

PDIP-14 **N SUFFIX** CASE 646-06 ISSUE P

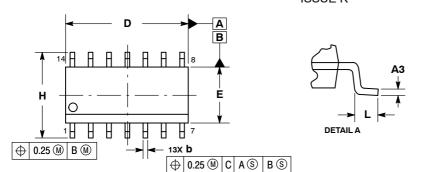


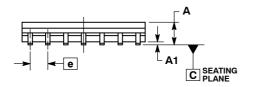
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

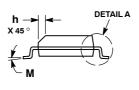
| | INCHES | | MILLIM | IETERS | |
|-----|--------|-------|----------|--------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.715 | 0.770 | 18.16 | 19.56 | |
| В | 0.240 | 0.260 | 6.10 | 6.60 | |
| С | 0.145 | 0.185 | 3.69 | 4.69 | |
| D | 0.015 | 0.021 | 0.38 | 0.53 | |
| F | 0.040 | 0.070 | 1.02 | 1.78 | |
| G | 0.100 | BSC | 2.54 BSC | | |
| Н | 0.052 | 0.095 | 1.32 | 2.41 | |
| J | 0.008 | 0.015 | 0.20 | 0.38 | |
| K | 0.115 | 0.135 | 2.92 | 3.43 | |
| L | 0.290 | 0.310 | 7.37 | 7.87 | |
| М | | 10 ° | | 10 ° | |
| N | 0.015 | 0.039 | 0.38 | 1.01 | |

PACKAGE DIMENSIONS

SOIC-14 NB CASE 751A-03 ISSUE K







- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.

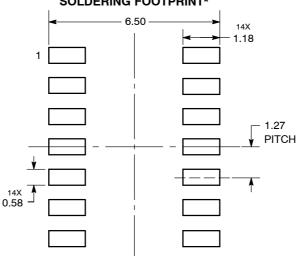
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.

 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

 - SIDE.

| | MILLIN | IETERS | INCHES | | |
|-----|--------|----------|--------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 1.35 | 1.75 | 0.054 | 0.068 | |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 | |
| АЗ | 0.19 | 0.25 | 0.008 | 0.010 | |
| b | 0.35 | 0.49 | 0.014 | 0.019 | |
| D | 8.55 | 8.75 | 0.337 | 0.344 | |
| Е | 3.80 | 4.00 | 0.150 | 0.157 | |
| е | 1.27 | 1.27 BSC | | BSC | |
| Н | 5.80 | 6.20 | 0.228 | 0.244 | |
| h | 0.25 | 0.50 | 0.010 | 0.019 | |
| L | 0.40 | 1.25 | 0.016 | 0.049 | |
| М | 0 ° | 7° | 0 ° | 7° | |

SOLDERING FOOTPRINT*

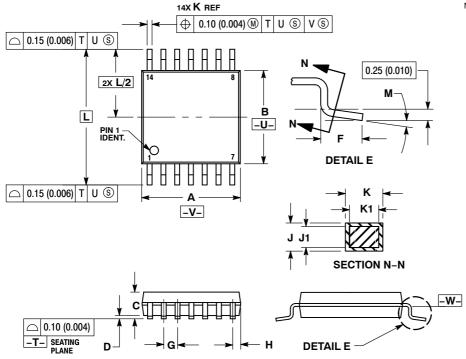


DIMENSIONS: MILLIMETERS

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-14 **DT SUFFIX** CASE 948G-01 ISSUE B



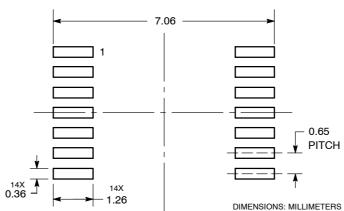
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER

 - 1. DIMENSIONING AND TOLERANCING PER
 ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD
 FLASH, PROTRUSIONS OR GATE BURRS.
 MOLD FLASH OR GATE BURRS SHALL NOT
 EXCEED 0.15 (0.006) PER SIDE.
 - DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
 - INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
 NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DÖES NOT INCLUDE
 DAMBAR PROTRUSION. ALLOWABLE
 DAMBAR PROTRUSION SHALL BE 0.08
 (0.003) TOTAL IN EXCESS OF THE K
 DIMENSION AT MAXIMUM MATERIAL
 CONDITION.
 - CONDITION.
 6. TERMINAL NUMBERS ARE SHOWN FOR
 - REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| | MILLIN | IETERS | INC | HES | |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 4.90 | 5.10 | 0.193 | 0.200 | |
| В | 4.30 | 4.50 | 0.169 | 0.177 | |
| С | | 1.20 | | 0.047 | |
| D | 0.05 | 0.15 | 0.002 | 0.006 | |
| F | 0.50 | 0.75 | 0.020 | 0.030 | |
| G | 0.65 | BSC | 0.026 BSC | | |
| Н | 0.50 | 0.60 | 0.020 | 0.024 | |
| J | 0.09 | 0.20 | 0.004 | 0.008 | |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 | |
| Κ | 0.19 | 0.30 | 0.007 | 0.012 | |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 | |
| L | 6.40 | BSC | 0.252 | BSC | |
| М | 0 ° | 8 ° | 0 ° | 8 ° | |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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